# mail

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



### Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





### SD1274-01 RF POWER BIPOLAR TRANSISTORS VHF MOBILE APPLICATIONS

#### FEATURES SUMMARY

- 160 MHz
- 13.6 VOLTS
- COMMON EMITTER
- POUT = 30 W MIN. WITH 10 dB GAIN

#### DESCRIPTION

The SD1274-01 is a 13.6 V Class C epitaxial silicon NPN planar transistor designed primarily for VHF communications. The SD1274-01 utilizes an emitter ballasted die geometry to withstand severe load mismatch conditions.

#### Figure 1. Package



#### **Figure 2. Pin Connection**



#### Table 1. Order Codes

| Order Codes | Marking   | Package | Packaging     |  |
|-------------|-----------|---------|---------------|--|
| SD1274-01   | SD1274-01 | M113    | PLASTIC TRAYS |  |

| Symbol            | Parameter                 | Value        | Unit |
|-------------------|---------------------------|--------------|------|
| V <sub>CBO</sub>  | Collector-Base Voltage    | 36           | V    |
| V <sub>CEO</sub>  | Collector-Emitter Voltage | 16           | V    |
| V <sub>CES</sub>  | Collector-Emitter Voltage | 36           | V    |
| V <sub>EBO</sub>  | Emitter-Base Voltage      | 4.0          | V    |
| lc                | Device Current            | 8.0          | Α    |
| P <sub>DISS</sub> | Power Dissipation         | 70           | W    |
| TJ                | Junction Temperature      | +200         | °C   |
| T <sub>STG</sub>  | Storage Temperature       | – 65 to +150 | °C   |

#### Table 2. Absolute Maximum Ratings (T<sub>case</sub> = 25°C)

#### Table 3. Thermal Data

| Symbol               | Parameter                        | Value | Unit |
|----------------------|----------------------------------|-------|------|
| R <sub>TH(j-c)</sub> | Junction-Case Thermal Resistance | 1.2   | °C/W |

#### ELECTRICAL SPECIFICATIONS (T<sub>CASE</sub> = 25°C)

#### Table 4. Static

| Symbol            | Test Conditions  | Value |      |      | Unit |
|-------------------|--|-------|------|------|------|
| Symbol            |  | Min.  | Тур. | Max. | Onit |
| BV <sub>CES</sub> | I <sub>C</sub> = 15 mA; V <sub>BE</sub> = 0 mA         |       | —    | —    | V    |
| BV <sub>CEO</sub> | I <sub>C</sub> = 50 mA; I <sub>B</sub> = 0 mA          | 16    | _    | _    | V    |
| BV <sub>EBO</sub> | I <sub>E</sub> = 5 mA; I <sub>C</sub> = 0 mA           | 4.0   | _    | _    | V    |
| I <sub>CBO</sub>  | V <sub>CB</sub> = 15 V; I <sub>E</sub> = 0 mA          | _     | —    | 5    | mA   |
| h <sub>FE</sub>   | $V_{CE} = 5 \text{ V}; \text{ I}_{C} = 250 \text{ mA}$ | 20    |      | _    |      |

#### Table 5. Dynamic

| Symbol          | Test Conditions                                  | Value |      |      | Unit |
|-----------------|--|-------|------|------|------|
| Symbol          |  | Min.  | Тур. | Max. | Gint |
| Роит            | f = 160 MHz; $P_{IN}$ = 3.0 W; $V_{CE}$ = 13.6 V | 30    | _    | —    | W    |
| GP              | f = 160 MHz; $P_{IN}$ = 3.0 W; $V_{CE}$ = 13.6 V | 10    | _    | _    | dB   |
| C <sub>OB</sub> | f = 1 MHz; V <sub>CB</sub> = 15 V                |       | 95   | —    | pF   |

57

#### **TYPICAL PERFORMANCE**

Figure 3. Power Output vs Supply Voltage (136 MHz)



### Figure 5. Power Output vs Supply Voltage (175 MHz)



## Figure 4. Power Output vs Supply Voltage (150 MHz)



#### Figure 6. Power Gain vs Frequency







#### Table 6. Impedance Data<sup>(1)</sup>

| FREQ.   | <b>Ζ<sub>ΙΝ</sub> (</b> Ω <b>)</b> | <b>Ζ<sub>CL</sub> (</b> Ω <b>)</b> |
|---------|------------------------------------|------------------------------------|
| 175 MHz | 1.0 + j 0.4                        | 2.3 + j 0.1                        |

Note: 1.  $\mathsf{P}_{\mathsf{IN}}$  = 3.0 W;  $\mathsf{V}_{\mathsf{CE}}$  = 12.5 V



#### PACKAGE MECHANICAL

| Gumbal | millimeters |     |       | inches |     |       |
|--------|-------------|-----|-------|--------|-----|-------|
| Symbol | Min         | Тур | Max   | Min    | Тур | Мах   |
| A      | 5.59        |     | 5.84  | 0.220  |     | 0.230 |
| В      | 19.94       |     |       | 0.785  |     |       |
| С      | 18.29       |     | 18.54 | 0.720  |     | 0.730 |
| D      | 24.64       |     | 24.89 | 0.970  |     | 0.980 |
| E      |             |     | 9.78  |        |     | 0.385 |
| F      | 0.10        |     | 0.15  | 0.004  |     | 0.006 |
| G      | 2.16        |     | 2.67  | 0.085  |     | 0.105 |
| Н      | 4.06        |     | 4.57  | 0.160  |     | 0.180 |
| I      |             |     | 7.11  |        |     | 0.280 |
| J      | 6.10        |     | 6.48  | 0.240  |     | 0.255 |

#### Table 7. M113 Mechanical Data

#### Figure 8. M113 Package Dimensions



Note: Drawing is not to scale.

#### **REVISION HISTORY**

#### Table 8. Revision History

| Date        | Revision | Description of Changes                |
|-------------|----------|---------------------------------------|
| June-1993   | 1        | First Issue                           |
| 24-May-2004 | 2        | Stylesheet update. No content change. |

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners

© 2004 STMicroelectronics - All rights reserved

STMicroelectronics GROUP OF COMPANIES

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States

www.st.com

